TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE

2SB1481

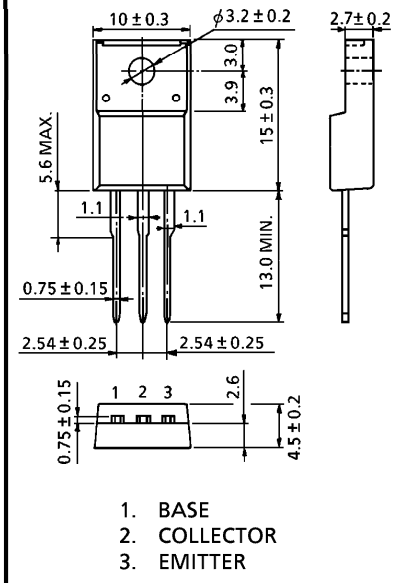
SWITCHING APPLICATIONS

- High DC Current Gain
  : h_{FE} = 2000 (Min.) (V_{CE} = −2V, I_C = −1.5A)
- Low Saturation Voltage : $V_{CE\ (sat)}$ = −1.5V (Max.) (I_C = −3A)
- Complementary to 2SD2241

MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	−100	V
Collector-Emitter Voltage		V_{CEO}	−100	V
Emitter-Base Voltage		V_{EBO}	−5	V
Collector Current	DC	I_C	±4	A
	Pulse	I_{CP}	±6	
Base Current		I_B	−0.3	A
Collector Power Dissipation	Ta = 25°C	P_C	2.0	W
	Tc = 25°C		25	
Junction Temperature		T_j	150	°C
Storage Temperature Range		T_{stg}	−55~150	°C

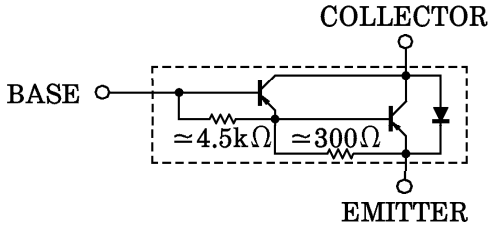
Unit in mm



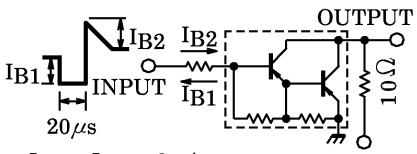
JEDEC	—
JEITA	SC-67
TOSHIBA	2-10R1A

Weight : 1.7g (Typ.)

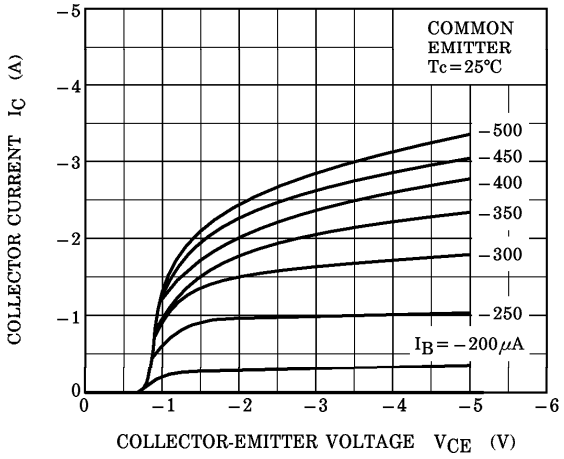
EQUIVALENT CIRCUIT



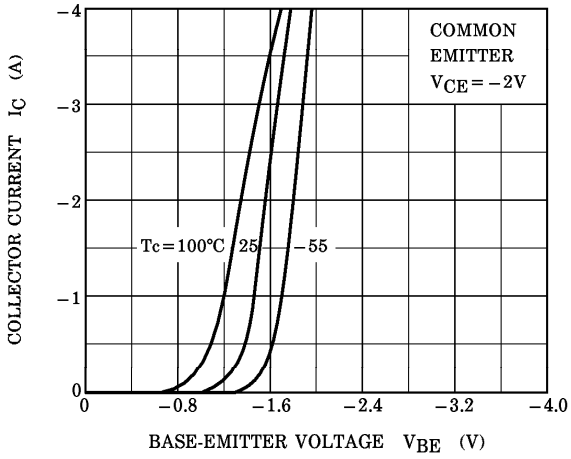
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I_{CBO}	$V_{CB} = -100V$, $I_E = 0$	—	—	−2.0	μA
Emitter Cut-off Current		I_{EBO}	$V_{EB} = -5V$, $I_C = 0$	—	—	−2.5	mA
Collector-Emitter Breakdown Voltage		$V_{(BR)CEO}$	$I_C = -10mA$, $I_B = 0$	−100	—	—	V
DC Current Gain		$h_{FE(1)}$	$V_{CE} = -2V$, $I_C = -1.5A$	2000	—	—	
		$h_{FE(2)}$	$V_{CE} = -2V$, $I_C = -3A$	1000	—	—	
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	$I_C = -3A$, $I_B = -6mA$	—	—	−1.5	V
Base-Emitter Saturation Voltage		$V_{BE(sat)}$	$I_C = -3A$, $I_B = -6mA$	—	—	−2.0	V
Collector-Emitter Reverse Voltage		V_{ECO}	$I_C = 1A$, $I_B = 0$	—	—	2.0	V
Switching Time	Turn-on Time	t_{on}	 $-I_{B1} = I_{B2} = 6mA$ DUTY CYCLE ≦ 1% $V_{CC} \fallingdotseq -30V$	—	0.15	—	μs
	Storage Time	t_{stg}		—	0.80	—	
	Fall Time	t_f		—	0.40	—	

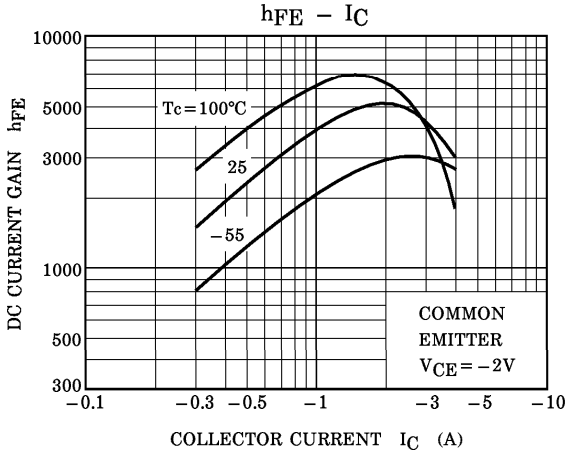
$I_C - V_{CE}$



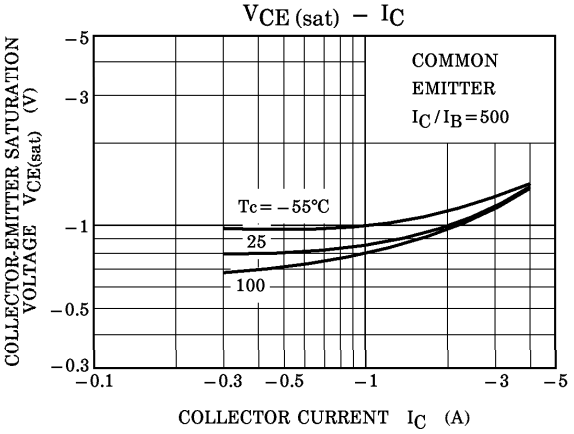
$I_C - V_{BE}$



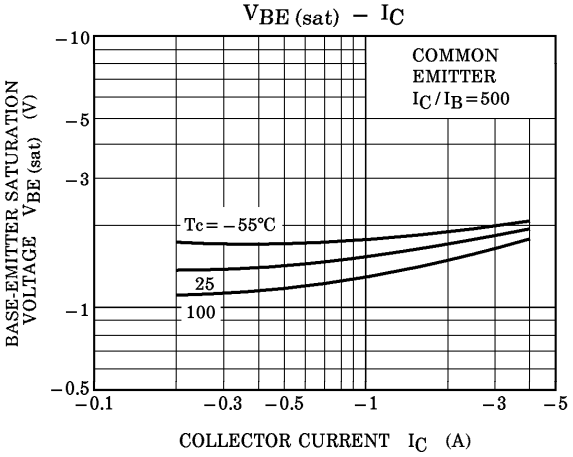
$h_{FE} - I_C$



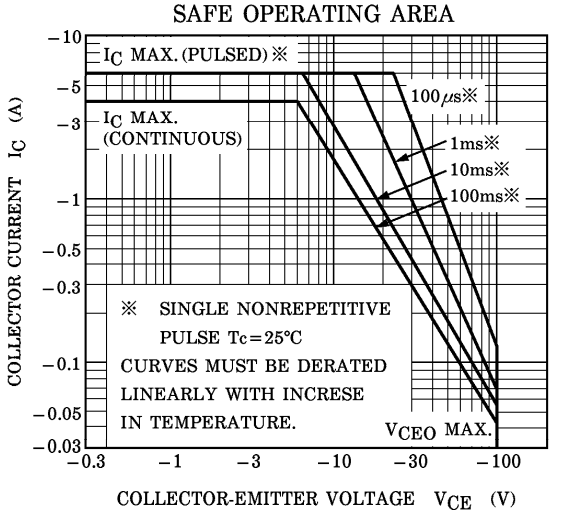
$V_{CE\,(sat)} - I_C$



$V_{BE\,(sat)} - I_C$



SAFE OPERATING AREA



RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.